MASTR Imperial

25-50 MHz, 60-WATT TRANSMITTER MODELS 4KT23A10



SPECIFICATIONS *

FCC Filing Designation

Frequency Range

Power Output

Crystal Multiplication Factor

Frequency Stability

Spurious and Harmonic Radiation

Modulation

Modulation Sensitivity

Audio Frequency Characteristics

Distortion

Deviation Symmetry

Maximum Frequency Spacing

Duty Cycle

KT-23-A

25-50 MHz

60 Watts (Adjustable from 20 to 60 Watts)

12

 $\pm 0.0005\%$ (-30°C to +60°C)

At least 80 dB below full rated power output

Adjustable from 0 to $\pm 5~\mathrm{kHz}$ swing with instantaneous modulation limiting.

50 - 100 Millivolts

Within +1 dB to -3 dB of a 6-dB/octave pre-emphasis from 300 to 3000 Hz per EIA standards. Post limiter filter per FCC and EIA.

Less than 3%

0.5 kHz maximum

±0.4%

EIA 20% Intermittent

hese specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

TABLE OF CONTENTS

SPECIFICATIONS	Cover
DESCRIPTION	1
CIRCUIT ANALYSIS	1
Exciter Oscillator Audio Amplifiers and Limiter Phase Modulator Emitter-Follower and Buffer-Amplifier Amplifier and Multipliers	1 2 2 2 2
Power Amplifier Amplifiers and PA	2 2
Channel Guard Encoder	3
Carrier Control Timer	3
MAINTENANCE	4
Disassembly PA Transistor Replacement Alignment Procedure Test Procedures	4 4 7 8
Power Output Tone Deviation Voice Deviation	8 8 8
Troubleshooting	9
OUTLINE DIAGRAM	10
SCHEMATIC DIAGRAM (with voltage readings)	11
PARTS LIST 12,13, 8	
PRODUCTION CHANGES	13
ILLUSTRATIONS	
Figure 1 Block Diagram	1 3 3 4 4

_WARNING___

No one should be permitted to handle any portion of the equipment that is supplied with voltage or RF power; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

DESCRIPTION

Transmitter Type KT-23-A is a crystal controlled, phase modulated transmitter designed for one-, two- or four-frequency operation in the 25-50 megahertz band. The transmitter consists of the following assemblies:

- Transistorized Exciter Board Audio, modulator, amplifier and multiplier stages.
- Transistorized PA Assembly Multiplier, amplifiers, driver, power amplifier and filter.
- Optional Channel Guard Board Encoder and tone network.

CIRCUIT ANALYSIS

The Transmitter provides a maximum power output of 60 Watts. The crystals range from approximately 2.14 to 4.17 megahertz, and the crystal frequency is multiplied 12 times.

A centralized metering jack (J102) is provided for use with GE Test Set Models 4EX3A10 (Rev. A or later) or 4EX8K11. The test set meters the amplifiers, multipliers and PA stage, and PA supply voltages. The metering jack also provides access to receiver audio, microphone and push-to-talk leads.

All input leads to the transmitter are individually filtered by the 20-pin feed-

through by-pass connector J101. Supply voltage, metering and control functions for the exciter board are connected from the PA assembly to jacks J1 through J18 on the exciter board.

EXCITER

OSCILLATOR

The transmitter uses a transistorized Colpitts oscillator (Q4). The oscillator provides a frequency stability of $\pm 0.0005\%$ without crystal ovens or warmers. Feedback for the oscillator is developed across C24.

In single-frequency transmitters, a jumper connects the Fl crystal keying lead to ground and the crystal frequency is applied to the base of oscillator Q4. The oscillator frequency is adjusted by trimmer C5. The oscillator output is applied to the anode of phase modulator CV1.

In multi-frequency transmitters, the single oscillator transistor is used, and up to three crystal circuits that are identical to the Fl crystal circuit are added. The keying jumper is removed, and the proper crystal frequency is selected by switching the crystal keying lead to ground by means of a frequency selector switch on the Control Unit. This forward biases the diode in the crystal circuit, reducing its impedance, so that the selected crystal frequency is applied to the base of oscillator Q4.

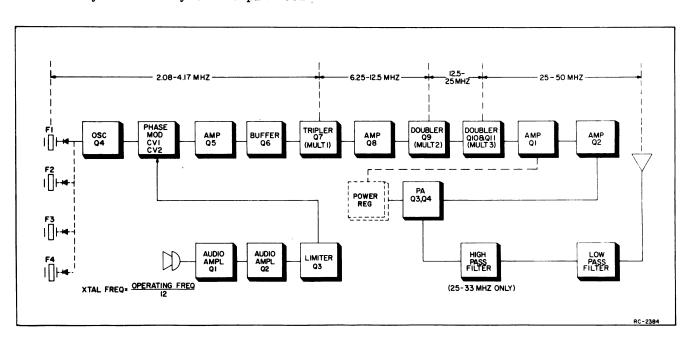


Figure 1 - Transmitter Block Diagram

AUDIO AMPLIFIERS AND LIMITERS

The audio section of the transmitter consists of DC-coupled feed-back amplifiers Q1, Q2 and Q3. Q3 also acts as a limiter at high audio input levels. Audio from the microphone is coupled through an input network (C2 and R1) to the audio stages. The input network, in conjunction with the feedback circuit, provides the audio gain and a 6-dB/octave pre-emphasis.

The output of limiter Q3 is connected through modulation adjust potentiometer R8 to a de-emphasis network for 6-dB/octave de-emphasis and post limiter roll-off. The network consists of C12, C13, R12 and R13. Modulation adjust R8 determines the maximum signal level applied to the modulator circuit, and is normally set for ±4.5 kHz (narrow band).

PHASE MODULATOR

The phase modulator uses varactors CV1 and CV2 (voltage-variable capacitors) in two cascaded R-L-C networks (R31-L2 and R32-L3). An audio signal applied to the modulator through L2 and L3 varies the capacitance of CV1 and CV2, resulting in a phase modulated output. The modulator output is applied to the base of emitterfollower Q5.

In Channel Guard applications, tone from the encoder-decoder board (on the receiver) is coupled to the modulator circuit through Channel Guard Mod Adjust potentiometer R35. This control is normally set for ± 0.75 kHz deviation as described in the transmitter Modulation Adjustment Procedure.

--NOTE-

If Channel Guard decode only is desired, disconnect the CHAN GD TONE HI lead from J8 of the transmitter exciter board.

EMITTER-FOLLOWER AND BUFFER-AMPLIFIER

Emitter-follower Q5 and buffer-amplifier Q6 isolates the modulator from the loading effects of the tripler stage, and provides some amplification. The output of Q6 is direct-coupled to the base of the tripler.

AMPLIFIER AND MULTIPLIERS

Q7 operates as a tripler (MULT-1) with collector tank Tl tuned to three times the crystal frequency. This stage is metered at Centralized Metering Jack J102 through R52. Following the tripler is amplifier Q8. This stage is metered at J102 through R62. The output of Q8 is capacitive-coupled from T2 to T3, and applied to the base of Q9.

Q9 operates as a doubler (MULT-2) the output of Q9 is capacitive-coupled from T4 to T5 to the base of Q10 and Q11, with both coils tuned to six times the crystal frequency. The stage is metered at J102 through R72.

Q10 and Q11 operate as a Class C, push-pull doubler (MULT-3) with collector tank T6 tuned to 12 times the crystal frequency. The doubler is metered at J102 through R82.

PA ASSEMBLY

-WARNING--

The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

AMPLIFIERS AND PA

The exciter output is capacity-coupled to two common-emitter, series-tuned RF amplifier stages, Al02-Q1 and Q2. Q1 base voltage is metered at J102-4 through metering network CR1, R1, R2 and C2.

Collector current for Q2 is metered across metering resistor R101 at J102-14 (AMP-2 Ic). The reading is taken on the 1-Volt scale (the actual current reading is 10 amperes full scale) with the GE Test Set in Position F. The amplifier output is coupled through a series-tuned circuit to base-balancing inductors L10-L15, and then to the bases of the power amplifiers.

Q3 and Q4 operate as parallel-connected, common-emitter power amplifiers to provide variable RF power output of 20-60 Watts from 25 to 50 MHz. Collector current for the PA transistors is metered across metering resistor R102 at J102-1 (PA Ic). The reading is taken on the 1-Volt scale (the actual current reading is 10 amperes full scale) with the GE Test Set in Position G, and with the HIGH SENSITIVITY button pressed.

Meter shunt R101 also serves as a voltage and current sensing element in conjunction with the Power Regulator to provide protection for the PA transistors by reducing the supply voltage of the pre-driver amplifier Q1 when the collector current or the supply voltage of the PA amplifiers (Q3, Q4) rises. Reducing the supply voltage of Q1 causes the RF drive to the PA transistors (Q3, Q4) to be reduced thus limiting the DC input power and holding the RF output power approximately constant.

The adjustable RF power output feature is accomplished by controlling the supply voltage of the pre-driver amplifier Q1. Potentiometer R13 on the Power Regulator board controls the RF power output by varying the supply voltage to the pre-driver amplifier Q1.

The Power Amplifier output is coupled through a series-tuned circuit to the high-pass filter, FL102, the low-pass filter FL101, then through the antenna relay K901 to the antenna.

CHANNEL GUARD ENCODER OPTION

Channel Guard Encoder Model 4EH18A10 is a fully transistorized encoder for use with MASTR Imperial combinations in encode only applications, or where different encode and decode tones are desired. The tone frequencies are controlled by plug-in tone networks that are made with precision components for excellent stability and reliability. The tone frequencies range from 71.9 to 203.5 Hz.

The encoder board and tone network mount on the underside on the transmitter chassis. Power, ground and tone output connections are made to transmitter exciter board AlO1 by means of a cable (19B216186G1).

The encoder tone is provided by selective oscillators Q1 and Q2, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q1, prevents any gain in the stage except at the desired encode frequency. The

oscillator output is applied to the base of emitter-follower Q3.

Thermistor-resistor combination R1 and RT1 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

The output of emitter-follower Q5 is applied to the phase modulator on the transmitter exciter board through Channel Guard MOD ADJUST R35. Instructions for setting R35 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

CARRIER CONTROL TIMER

The Carrier Control Timer option shuts off the transmitter on each transmission after a one-minute timing cycle, and alerts the operator that the transmitter is off by means of an alarm tone in the speaker. The transmitter can be turned on again by releasing and rekeying the push-to-talk switch on the microphone.

The timing cycle (transmitter keyed time) is normally set at the factory for a duration of one minute. An optional potentiometer is available that permits the timing cycle to be adjusted from 15 seconds to 5 minutes. Complete instructions for the Carrier Control Timer are contained in Maintenance Manual LBI-4138.

MAINTENANCE

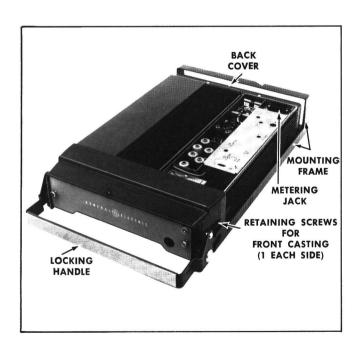


Figure 2 - Top Cover Removed



Figure 3 - Bottom Cover Removed

DISASSEMBLY

To service the transmitter from the top (Figure 2):

- Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of trans-
- 3. Slide cover back and lift off.

To service the transmitter from the bottom (Figure 3):

- 1. Pull locking handle down. Pull radio out of mounting frame.
- Remove two screws in bottom cover.
 Pry up at back of transmitter.
- 3. Slide cover back and lift off.

To remove transmitter from system frame:

- Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.
- 2. Remove the four screws in the back cover.
- 3. Remove the two screws holding the transmitter at each end of the system frame.
- 4. Disconnect the antenna plug and receiver plug in front of the transmitter and the 20-pin feed-thru connector at the back of the transmitter, and slide the unit out of the system frame.

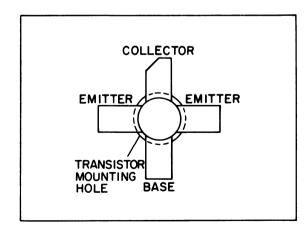
PA TRANSISTOR REPLACEMENT



The stud mounted RF Power Transistors used in the transmitter contain Beryllium Oxide, a TOXIC substance. If the ceramic or other encapsulation is opened, crushed, broken or abraded, the dust may be hazardous if inhaled. Use care in replacing transistors of this type.

To replace the PA transistors (Q1 through Q4):

- 1. Unsolder one lead at a time with a 50-Watt soldering iron. Use a scribe to hold the lead away from the printed circuit board until the solder cools.
- 2. Turn the transmitter over.
- 3. Hold the body of the transistor to prevent it from turning. Remove the transistor hold-down nut and spring washer through the hole in the heatsink with an 11/32-inch nut-driver. Lift out the transistor, and remove the old solder from the printed circuit board.
- 4. Trim the new transistor leads (if required) to approximately 3/8-inch lengths. Cut the collector lead at a 45° angle for future identification (see Figure 4). The letter "C" on the top of the transistor indicates the collector.
- 5. Apply a coating of silicone grease around the transistor mounting surface, and place the transistor in the mounting hole. Align the leads as shown in the Outline Diagram. Then hold the body of



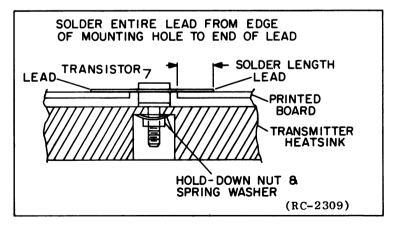


Figure 4 - Lead Identification

Figure 5 - Lead Forming

- the transistor and replace the hold-down nut and spring washer, using moderate torque (8 to 10 inch-pounds maximum in 25-50 MHz transmitters, and 6.5 inch-pounds for 150.8 to 470 MHz transmitters).
- 6. Make sure that the transistor leads are formed as shown in Figure 5 so that the leads can be soldered to the printed circuit pattern, starting from the inner edge of the mounting hole.
- 7. Solder the leads to the printed circuit pattern. Start at the inner edge of mounting hole and solder the remaining length of transistor lead to the board.

-CAUTION-

Failure to solder the transistor leads as directed may result in the generation of RF loops that could damage the transistor.

MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R8) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

TEST EQUIPMENT

- 1. An audio oscillator (GE Model 4EX6A10)
- 2. A frequency modulation monitor
- 3. An output meter of a VTVM
- 4. GE Test Set Models 4EX3A10 or 4EX8K10,11

PROCEDURE

- Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across J5 (Mike High) and J6 (Mike Low) on the Exciter Board
- Apply a 0.75-volt signal at 1000 Hz to Test Set or across J5 and J6 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R8) for a 4.5-kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R35) for 0.75 kHz tone deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Apply a 0.75-Volt signal at 1000 Hz and set MOD ADJUST (R8) for a 3.75 kHz deviation (4.5 kHz minus 0.75 kHz tone deviation).
- 5. For multi-frequency transmitters, set the deviation as described in Steps 3 and 4 on the channel producing the largest amount of deviation.

PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA supply voltage and PA current, and using the following formula:

P_i = PA voltage x PA current

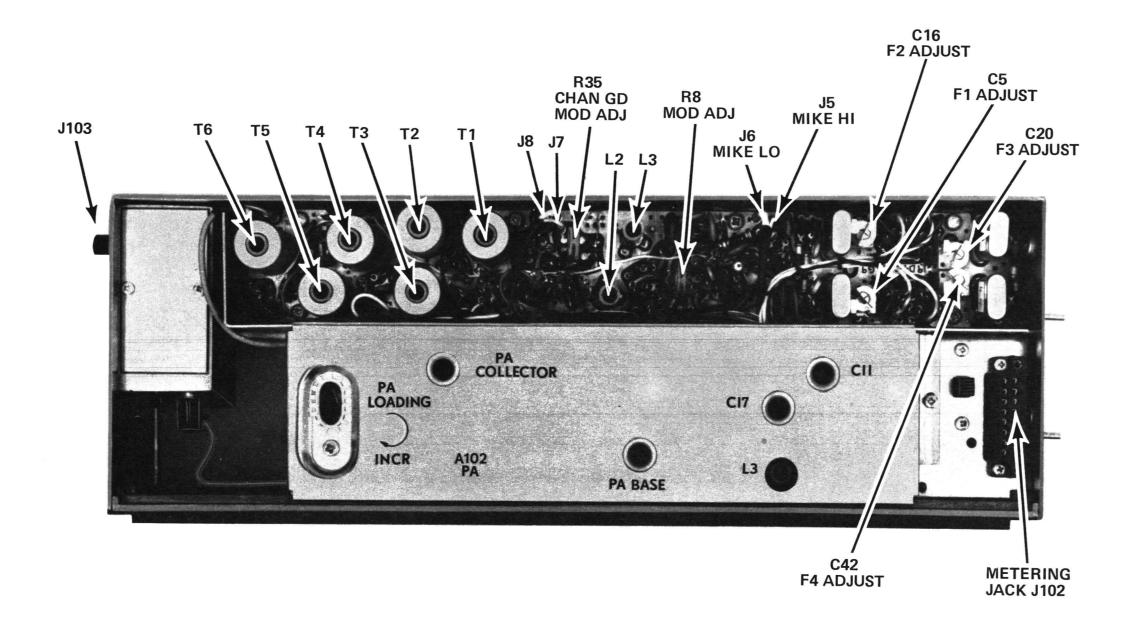
where

P_i is the power input in watts,

PA voltage is measured with the GE Test Set in Position G on the 15 volt scale, and polarity switch in the (-) position.

PA current is measured with the Test Set in Position G in the Test 1 position, and with the HIGH SENSITIVITY button pressed (10 amperes full scale).

Example: P_i = 12.5 volts x 7 amperes = 87.5 watts



TRANSMITTER ALIGNMENT

EQUIPMENT REQUIRED

- 1. GE Test Set Model 4EX3AlO (Revision A or later), or Model 4EX8Kll.
- 2. A 50-ohm wattmeter connected to J103.
- A frequency counter.

PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place crystal(s) in crystal socket (crystal frequency = operating frequency ÷ 12).
- 2. For a large change in frequency or a badly mis-aligned transmitter, set crystal trimmer C5 to mid-capacity. In multi-frequency transmitters, set all trimmers to mid-capacity and set the channel selector switch to the F1 position.
- 3. For a large change in frequency or a badly mis-aligned transmitter, turn the slugs in exciter coils L2, L3, T1 thru T6 and L3 on PA board A102 (if present) so that the top of the slug is approximately even with the bottom of the coil winding or until the slugs hit the board (whichever comes first). Turn mica compression capacitors C11, C17, PA BASE, PA COLLECTOR, and PA LOADING (on PA board) all the way to the right (clockwise). Then set each capacitor 1-1/2 turns counterclockwise.
- 4. Connect the GE Test Set to receiver metering jack J442 and check for +10 Volts at Position J. If reading is not 10 Volts, refer to the Power Regulator Outline Diagram and set R28 for +10 Volts.
- 5. Set the Power Regulator Power Adjust pot (R13) fully clockwise.
- 6. Connect GE Test Set to metering jack J102. Set the test polarity to + and set the range to the Test 1 (or 1-Volt position for 4EX8K11) for all adjustments. Voltage readings at Position "F" may be converted to driver collector current by multiplying the reading by 10 (10 amperes full sqale). Voltage readings at Position "G" (with HIGH SENSITIVITY button pressed) may be converted to PA collector current by multiplying the reading by 10 (10 amperes full scale).
- 7. All adjustments are made with the transmitter keyed. Unkey the transmitter between steps to avoid unnecessary heating.

TRANSMITTER ALIGNMENT PROCEDURE

STEP	METER POSITION	TUNING CONTROL	METER READING	PROCEDURE			
				EXCITER BOARD			
1.	A MULT-1	L2 and L3	Maximum	Carefully tune L2 and L3 for maximum meter reading.			
2.	A MULT-1	T1	Minimum	Tune Tl for a small dip in meter reading.			
3.	B AMP-1	T1 and T2	See Pro- cedure	Tune T1 for maximum meter reading and then tune T2 for a small dip or movement of meter indicator.			
4.	C MULT-2	T3, T2 and T4	See Pro- cedure	Tune T3 and then T2 for maximum meter reading. Then tune T4 for a small dip or movement of meter indicator.			
5.	D MULT-3	T5, T4 and T6	See Pro- cedure	Tune T5 and then T4 for maximum meter reading. Then tune T6 for a dip in meter reading.			
				PA BOARD			
6.	E AMP-2/3	L3/L27 and T6 (Exciter)	Maximum	Tune L3/L27 and T6 for maximum meter reading.			
7.	F DRIVER IC	C17, C11	Maximum	une C17 for maximum meter reading. If no indication on meter, adjust C11 lightly clockwise and re-tune C17 for maximum meter reading.			
8.	F DRIVER IC	PA BASE (C18)	Maximum	Tune PA BASE for maximum power output on wattmeter.			
9.	G PA Ic		See Pro- cedure	With the HIGH SENSITIVITY switch pressed, check meter reading for 1.0-Volt. If reading exceeds 1.0-Volt, adjust PA LOADING for a meter reading of 0.8-Volt.			
10.	G PA Ic	PA COLLECTOR (C27)	Maximum	Tune PA Collector for maximum power output on wattmeter.			
11.	G	PA LOADING & PA Collector (C28/C29) C27	1.0 Volts Maximum	Press the HIGH SENSITIVITY switch. Then adjust PA LOADING slightly clockwise and tune PA COLLECTOR for maximum power output. Repeat until the meter reads 1.0 Volts maximum. NOTE————————————————————————————————————			
				Reading will increase only when PA COLLECTOR is re-tuned for maximum power output following each slight clockwise adjustment for PA LOADING.			
12.	G	C17, PA BASE & PA COLLECTOR	Maximum	Tune C18, PA BASE AND PA COLLECTOR for maximum power output on wattmeter.			
13.	G		1.0 Volts Maximum	Press HIGH SENSITIVITY switch and check for meter reading of 1.0 Volts maximum. If necessary, repeat Step 11 until proper reading is obtained.			
				FREQUENCY ADJUSTMENT			
14.		C5 (C16 in 2-freq. units, and C20 or C42 in multi-freq. units).		Loosely couple frequency counter to output and adjust C5 for proper frequency output. (Switch to F2 and adjust C16 on 2-frequency units. In 3- or 4-frequency units, adjust C20 or C42 as required). NOTE			
				For proper frequency control of the transmitter, it is recommended that all frequency adjustments be made when the equipment is at a temp. of approximately 75°F. In no case should frequency adjustments be made when the equipment is outside the temp. range of 50° to 90° F.			
15.	G	R13		Adjust R13 on Power Regulator for 60 Watts or other desired power, down to 20 Watts.			

ALIGNMENT PROCEDURE

LBI-4426

25-50 MHz, 60-WATT TRANSMITTER TYPE KT-23-A

Issue 1

LBI-4426

TEST PROCEDURES

These Test Procedures are designed to assist you in servicing a transmitter that is operating-but not properly. Problems encountered could be low power output, low B plus, tone and voice devi- Transmitter Troubleshooting Procedure. Before ation, defective audio sensitivity and modulator adjust control set too high. By following the sequence of test steps starting with Step 1, the

defect can be quickly localized. Once a defect is pin-pointed, refer to the "Service Check" and the additional corrective measures included in the starting with the Transmitter Test Procedures, be sure the transmitter is tuned and aligned to the proper operating frequency.

TEST EQUIPMENT REQUIRED

for test hookup as shown:

1. Wattmeter similar to: 2. VTVM similar to: 3. Audio Generator similar to: 4. Deviation Meter (with

Bird # 43 Jones # 711N Triplett # 850 Heath # 1M-21

GE Model 4EX6A10 or Heath # 1G-72

a .75 kHz scale) similar to: Measurements # 140 Lampkin # 205A

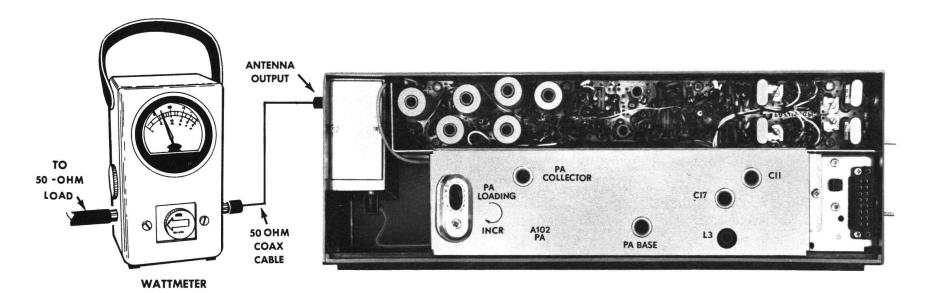
5. Multimeter similar to:

GE TEST SET MODEL 4EX3A10. MODEL 4EX8K11 or 20,000 ohms-per-volt voltmeter

STEP 1

POWER MEASUREMENT TEST PROCEDURE

1. Connect transmitter output to wattmeter as shown below:



2. Turn Power Adjust R13 (Power Regulator) full clockwise. Key transmitter and check wattmeter for minimum reading of 60 Watts. Reset Power Adjust, R13, to the desired power out.

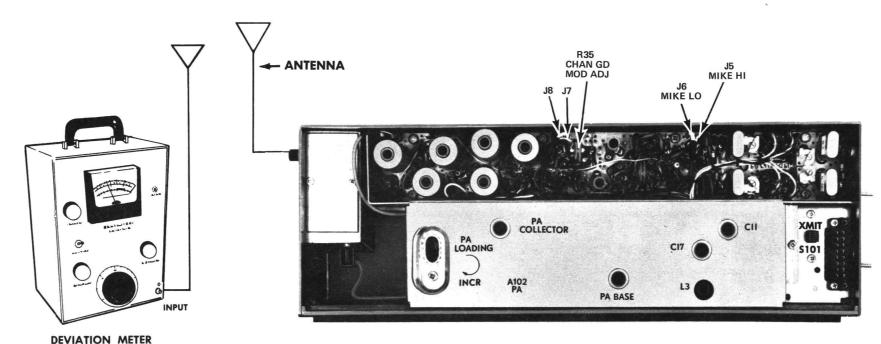
SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

STEP 2

TONE DEVIATION WITH CHANNEL GUARD TEST PROCEDURE

1. Set up Deviation Meter and monitor output of transmitter as shown below:



- 2. Unplug the MIC HI terminal from J5 on Transmitter Exciter Board.
- 3. Key transmitter and check for 0.75-kHz deviation. If reading is low or high, adjust Channel Guard MOD ADJUST (R35) for a reading of 0.75-kHz.

NOTES: -- The Channel Guard MOD ADJUST (R35) may be adjusted for deviations up to 1.0 kHz maximum for all tone frequencies.

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be peaked carefully to insure proper performance. (Refer to Steps 1 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated every time the Tone Frequency is changed.

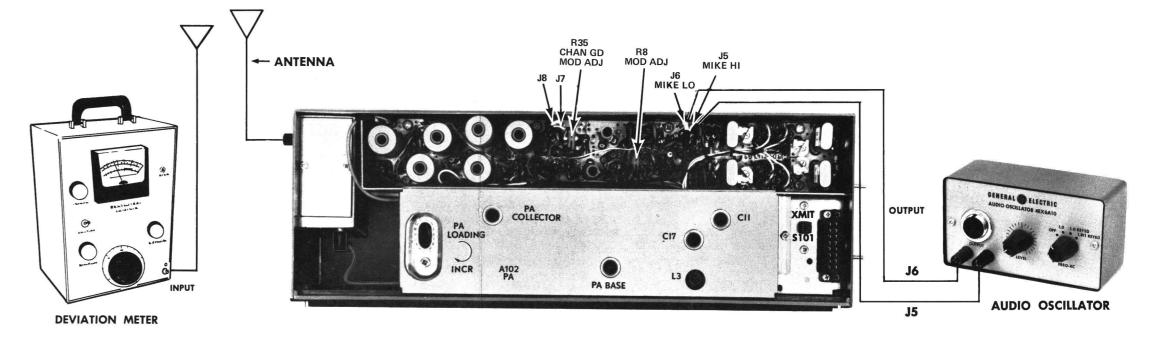


DEVIATION METER

STEP 3

VOICE DEVIATION AND SYMMETRY TEST PROCEDURE

- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks J5 and J6.
- 2. Connect test equipment to transmitter as shown below:

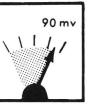


- 3. Set the generator output to 1.0 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- 5. Deviation reading should be ±4.5 kHz.
- 6. Adjust Modulation Adjust Control R8 until deviation reads 4.5 kHz on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.
- NOTES: --Imperial transmitters are adjusted for 4.5 kHz deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5.0 kHz under the worst conditions of frequency, voltage and temperature.

If the deviation reading plus (+) or minus (-) differs by more than 0.5 kHz, check the following:

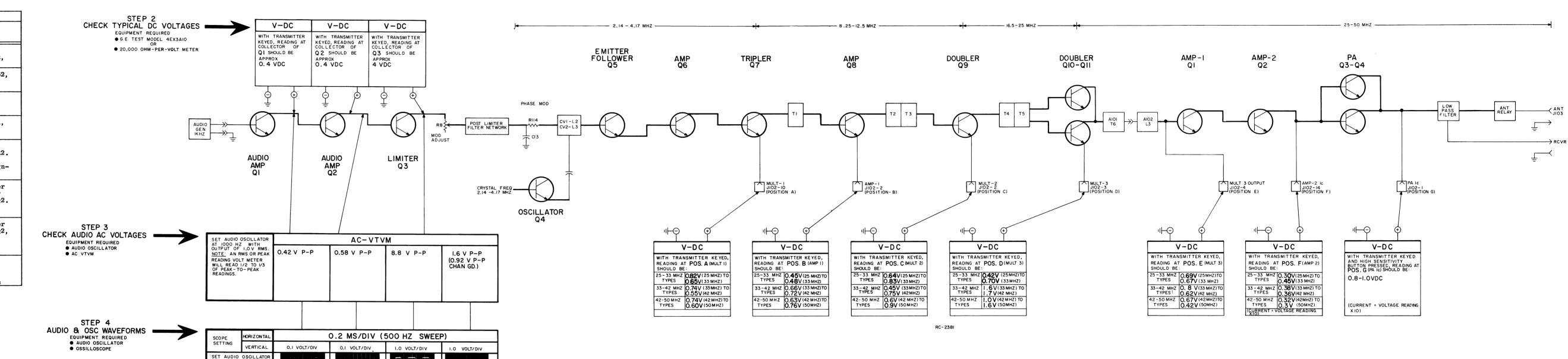
- 1. Recheck Step 1 as shown in the Transmitter Alignment Chart.
- 2. Check Audio Sensitivity by reducing generator output until deviation falls to 3.0 kHz. Voltage should be LESS than 100 millivolts.





STEP I - QUICK CHECKS

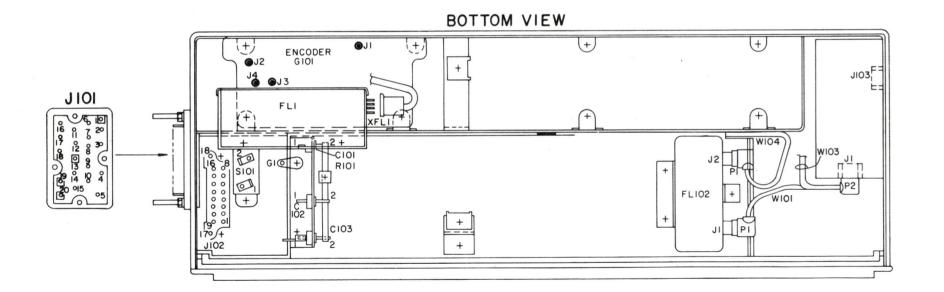
High Meter Reading Q6, Q7, 10- Volt Regula- tor Q8, R60, R61, T2, 10-Volt	Low Meter Reading Q4, Q5, Q6, Q7 L2, L3, 10- Volt Regulator T1, Q8, R60,	Zero Meter Reading Q4, Q5, Q6, Q7, Crystal, 10-Volt, Gnd to Osc Ch.
Volt Regula - tor Q8, R60, R61, T2, 10-Volt	L2, L3, 10- Volt Regulator	Crystal, 10-Volt,
T2, 10-Volt	T1 08 R60	
Regulator	C60, R61, 10- Volt Reg.	Q8, R61, C60, R62, T2, 10-Volt Reg.
T2, T3, Q8, R68, R71, T4	T2, T3, Q8, R68, C70, R71 T4	Q8, T3, T4, R70, R72, C71
T4, T5, Q10, R80, R83	T4, T5, Q10, C80, R83, C82, Q11	T4, T5, Q10, Q11, R83, C82, T6
Q10, Q11, L3B, L3C, L27, Check Trans- mitter Align- ment.	Q10, Q11, L3B, L3C, L27, Check Trans- mitter Align- ment	Q10, Q11, L3B, L3C, L27, CR1/CR2. C11, C17, Check Transmitter Align- ment.
Check Trans- mitter Align- ment, Power Regulator.	Check Trans- mitter Align- ment, Power Regulator, Q1, Q2.	Check Transmitter Alignment, Power Regulator, Q1, Q2.
Check Trans- mitter Align- ment, Q3, Q4, Antenna	Check Trans- mitter Align- ment, Q3, Q4, Antenna, Power Regulator	Check Transmitter Alignment, Q1, Q2, Q3, Q4, Antenna, Power Regulator
Power	Power	Short/Fuse Blown
	Regulator T2, T3, Q8, R68, R71, T4 T4, T5, Q10, R80, R83 Q10, Q11, L3B, L3C, L27, Check Transmitter Alignment. Check Transmitter Alignment, Power Regulator. Check Transmitter Alignment, Q3, Q4, Antenna	Regulator T2, T3, Q8, R68, R71, T4 T4, T5, Q10, R80, R83 Q10, Q11, L3B, L3C, L27, Check Transmitter Alignment, Power Regulator. Check Transmitter Alignment, Q3, Q4, Antenna Power T2, T3, Q8, R68, C70, R71 T4 T4, T5, Q10, C80, R83, C82, Q11 Q10, Q11, L3B, L3C, L27, Check Transmitter Alignment Check Transmitter Alignment, Power Regulator, Q1, Q2.



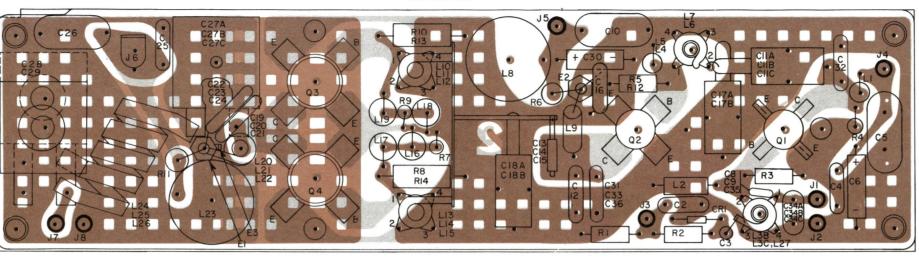
TROUBLESHOOTING PROCEDURE

25-50 MHz, 60-WATT TRANSMITTER TYPE KT-23-A

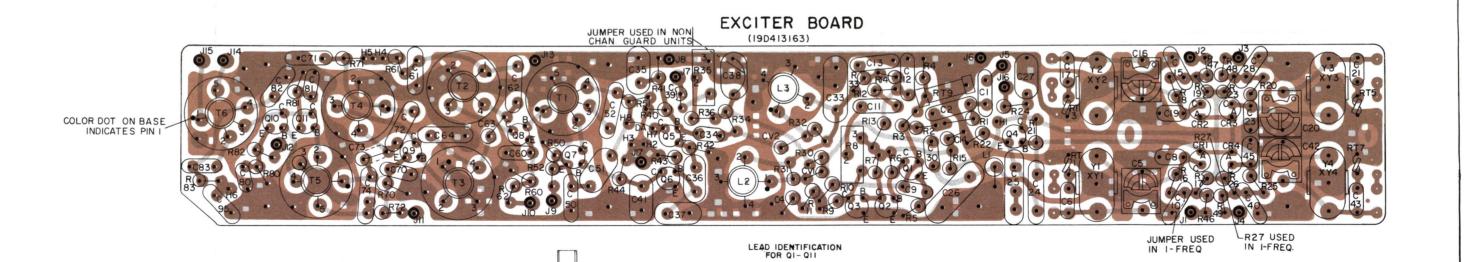
TOP VIEW PA BOARD AIO2 PA BOARD AIO2 EXCITER BOARD AIO1 AIO1 FLIOIA FLIOIB FLIOIC FLIOIB FLIOIC FLIOIB FLIOIC FLIOIB FLIOIC FLIOIB FLIOIC FLIOIB FLIOIC FLIOIB FLIOID FLIOIB F







16097, Sh. 1, Rev. 3)



IN-LINE TRIANGULAR
VIEW FROM LEAD END

NOTE: LEAD ARRANGEMENT, AND NOT CASE SHAPE, IS DETERMINING FACTOR FOR LEAD IDENTIFICATION.

EXCITER BD ONLY

الال

CATHODE ANODE

LEAD IDENTIFICATION

FOR CRI THRU CR4

EXCITER BD. ONLY

RUNS ON SOLDER SIDE

RUNS ON BOTH SIDES

RUNS ON COMPONENT SIDE

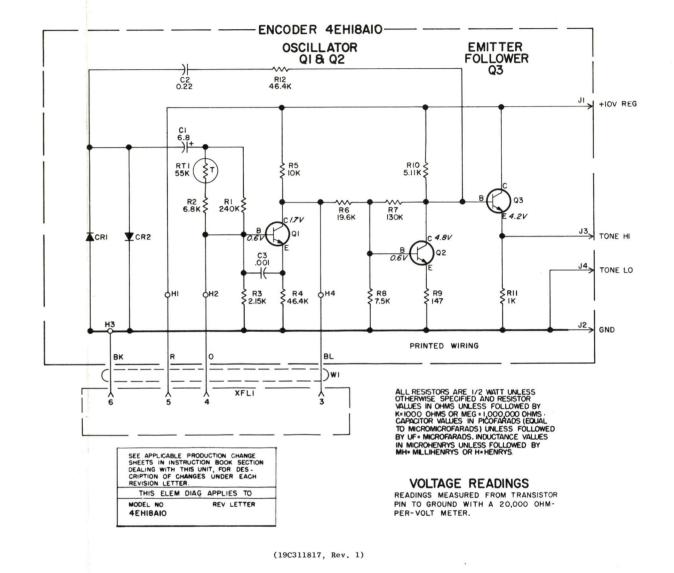
25-50 MHz, 60-WATT TRANSMITTER TYPE KT-23-A

OUTLINE DIAGRAM

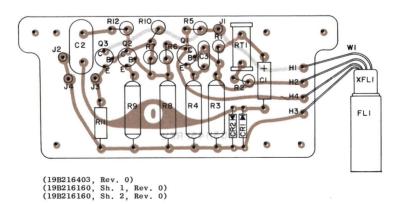
(19R621955, Rev. 1)

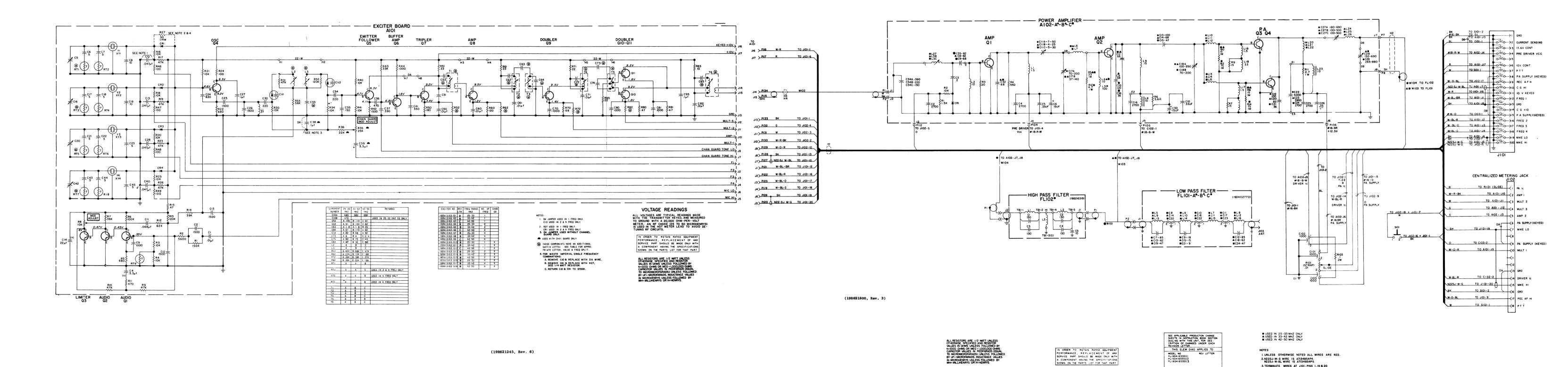
CHANNEL GUARD ENCODER MODEL 4EH18A10

SCHEMATIC DIAGRAM



OUTLINE DIAGRAM





(19R621245, Rev. 6)

SCHEMATIC DIAGRAM

25-50 MHz, 50-WATT TRANSMITTER TYPE KT-23-A

Issue 2

1. UNLESS OTHERWISE NOTED ALL WIRES ARE N22.

2.N22SJ-W-G WIRE IS A7134854P4. N22SJ-W-BL WIRE IS A7134854P5. 3. TERMINATE WIRES AT JIOI-PINS 1, 19 & 20 WITH 19A115793.

PARTS LIST LBI-4411A 25-50 MHZ TRANSMITTER TYPE KT-23-A

SYMBOL	GE PART NO.	DESCRIPTION
AlOlA thru AlOlC		EXCITER BOARD Alola 19D413163G7 25-33 MHz Alolb 19D413163G8 33-42 MHz Alolc 19D413163G9 42-50 MHz
C1	19A116080P1	
C2	7491395P111	Polyester: 0.01 \(\mu f \pm 20\%, 50 \) VDCW. Ceramic disc: 1500 \(\mu f \pm 10\%, 500 \) VDCW; \(\mi m \) to
C4	5496267P9	RMC Type JL. Tantalum: 3.3 µf ±20%, 15 VDCW; sim to Sprague
C5	5491271P105	Type 150D. Variable, sub-miniature: approx 1.9-10.5 pf,
CO	04912711103	750 v peak; sim to EF Johnson 189.
C6	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0
C7*	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0 Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
C8	5496219P41	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
С9	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C10	19A116080P5	Polyester: 0.047 µf ±20%, 50 VDCW.
C11	19A116080P6	Polyester: 0.068 µf ±20%, 50 VDCW.
C12 and C13	7491395P111	Ceramic disc: 1500 pf \pm 10%, 500 VDCW; sim to RMC Type JL.
C14	5496267P10	Tantalum: 22 µf ±20%, 15 VDCW; sim to Sprague Type 150D.
C15	19A116080P5	Polyester: 0.047 µf ±20%, 50 VDCW.
C16	5491271P105	Variable, sub-miniature: approx 1.9-10.5 pf, 750 v peak; sim to EF Johnson 189.
C17	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0
C18*	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0 Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
C19	5496219P41	Ceramic disc: 10 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.
C20	5491271P105	Variable, sub-miniature: approx 1.9-10.5 pf, 750 v peak; sim to EF Johnson 189.
C21	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0
C22*	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0 Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
C23	5496219P36	Ceramic disc: 5 pf ±0.25 pf, 500 VDCW, temp co 0 PPM.
C24	5496372P178	Ceramic disc: 820 pf ±5%, 500 VDCW, temp coef -3300 PPM.
C25 and C26	5493367P1500K	Mica: 1500 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.
C27	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.
C28	19A116080P5	Polyester: 0.047 µf ±20%, 50 VDCW.
C30	5496372P350	Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef -4700 PPM.
C33A	7147203P4	Silver mica: 680 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-20.
C34	5496372P350	Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef -4700 PPM.
034		Mica: 150 pf ±10%, 100 VDCW; sim to

YMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
C36	5493366P470K	Mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	=		DIODES AND RECTIFIERS	R30	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
C37	5493366P390K	Mica: 390 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	CR1 thru CR4	19A115603P1	Silicon.	R31 R32	3R77P473J 3R77P124J	Composition: 47,000 ohms ±5%, 1/2 w. Composition: 0.12 megohm ±5%, 1/2 w.
C40	19A116080P5	Polyester: 0.047 µf ±20%, 50 VDCW.	CV1	5495769P8	Varactor, silicon: 33 µf ±20% at 4 VDC; sim to	R33	3R77P563K	Composition: 56,000 ohms ±10%, 1/2 w.
C41	5493366P330K	Mica: 330 pf ±10%, 100 VDCW; sim to	and CV2		Pacific Śemiconductors Varicap Type V-595.	R34	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
C42	5491271P105	Electro Motive Type DM-15. Variable, sub-miniature: approx 1.9-10.5 pf,			JACKS AND RECEPTACLES	R40 and	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
		750 v peak; sim to EF Johnson 189.	J1 thru	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	R41		
C43	19C300685P93	Ceramic disc: 5 pf ±2%, 500 VDCW, temp coef 0 PPM.	J17			R42	3R77P152K	Composition: 1500 ohms ±10%, 1/2 w.
C44*	19C300685P93	Ceramic disc: 5 pf ±2%, 500 YDCW, temp coef 0 PPM. Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.	ш	7488079P48		R43	3R77P333K 3R77P102K	Composition: 33,000 ohms ±10%, 1/2 w. Composition: 1000 ohms ±10%, 1/2 w.
C45	5496219 P3 6	Ceramic disc: 5 pf ±0.25 pf, 500 VDCW, temp coef			sim to Jeffers 4422-9K.	R46	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.
C50	19B209243P1	0 PPM. Polyester: 0.01 μf ±20%, 50 VDCW.	L2A L2B	19D402808G15 19D402808G16	Coil. Includes tuning slug 5491798Pl. Coil. Includes tuning slug 5491798Pl.	thru R49		
C51	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.	L2C	19D402808G17	Coil. Includes tuning slug 5491798P1.	R50	3R77P181K	Composition: 180 ohms ±10%, 1/2 w.
C52A	5496219P263	Ceramic disc: 100 pf ±5%, 500 VDCW, temp coef	L3A	19D402808G15	Coil. Includes tuning slug 5491798P1.	R51	3R77P330K	Composition: 33 ohms ±10%, 1/2 w.
C52B	5496219 P2 64	-80 PPM. Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef	L3B	19D402808G16	Coil, Includes tuning slug 5491798P1.	R52A R52B	3R77P823K 3R77P683K	Composition: 82,000 ohms ±10%, 1/2 w. Composition: 68,000 ohms ±10%, 1/2 w.
COZB	J490219F204	-80 PPM.	L3C	19D402808G17	Coil. Includes tuning slug 5491798Pl.	R52C	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.
C52C	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef -80 PPM.			TRANSISTORS	R60	3R77P121K	Composition: 120 ohms ±10%, 1/2 w.
C60	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.	Q1	19A115889P1	Silicon, NPN; sim to Type 2N2712.	R61	3R77P220K	Composition: 22 ohms ±10%, 1/2 w.
and C61			thru Q3			R62A	3R77P273K	Composition: 27,000 ohms ±10%, 1/2 w.
C62A	5496219P262	Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q4	19A115330P1	Silicon, NPN.	R62B	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.
C62B	5496219P263	Ceramic disc: 100 pf ±5%, 500 VDCW, temp coef	Q5	19A115123P1	Silicon, NPN; sim to Type 2N2712.	R62C	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
C62C	5496219 P2 61	-80 PPM. Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef	Q6 thru Q9	19A115330P1	Silicon, NPN.	R70 R71	3R77P680K 3R77P220K	Composition: 68 ohms ±10%, 1/2 w. Composition: 22 ohms ±10%, 1/2 w.
0020	01002101201	-80 PPM.	Q10	19A116201P1	Silicon, NPN.	R72A	3R77P393K	Composition: 39,000 ohms ±10%, 1/2 w.
C63A	5491601P124	Phenolic: 1.8 pf ±5%, 500 VDCW.	and Q11			R72B	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.
C63B C64A	5491601P127 5496219P262	Phenolic: 2.4 pf ±5%, 500 VDCW. Ceramic disc: 91 pf ±5%, 500 VDCW, temp coef			RESISTORS	R72C	3R77P273K	Composition: 27,000 ohms ±10%, 1/2 w.
COAN	3490219P202	-80 PPM.	R1	3R77P154K	Composition: 0.15 megohm ±10%, 1/2 w.	R80 and	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.
C64B	5496219P264	Ceramic disc: 110 pf ±5%, 500 VDCW, temp coef -80 PPM.	R2	3R77P562K	Composition: 5600 ohms ±10%, 1/2 w.	R81		
C64C	5496219 P2 61	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -80 PPM.	R3 and R4	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	R82A R82B	3R77P393K 3R77P223K	Composition: 39,000 ohms ±10%, 1/2 w. Composition: 22,000 ohms ±10%, 1/2 w.
C70	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	R5	3R77P681K	Composition: 680 ohms $\pm 10\%$, $1/2$ w.	R82C	3R77P183K	Composition: 22,000 ohms ±10%, 1/2 w. Composition: 18,000 ohms ±10%, 1/2 w.
		RMC Type JF Discap.	R6	3R77P104K	Composition: 0.10 megohm ±10%, 1/2 w.	R83	3R77P100K	Composition: 10 ohms ±10%, 1/2 w.
C71 C72A	19A116080P1 5496219P261	Polyester: 0.01 µf ±20%, 50 VDCW.	R7	3R77P393K	Composition: 39,000 ohms ±10%, 1/2 w.			THERMISTORS
C72A	3490219P201	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -80 PPM.	R8	19B209358P106	Variable, carbon film: approx 75 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	RT1A	19B209284P12	Disc: 600 ohms DC res; sim to GE 16D2134,
C72B	5496219P259	Ceramic disc: 68 pf ±5%, 500 VDCW, temp coef -80 PPM.	R9	3R77P473J	Composition: 47,000 ohms ±5%, 1/2 w.	RT1B	19B209284P9	Disc: 330 ohms DC res; sim to GE 16D3119.
C73A	5496219P39	Ceramic disc: 8 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	and R10 R11	3R77P471J	Composition: 470 ohms ±5%, 1/2 w.	RT2*	19B209284P13	Rod: 3200 ohms DC res; sim to GE 1R1126. Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
С73В	5496219P35	Ceramic disc: 4 pf ±0.25 pf, 500 VDCW, temp coef 0 PPM.	R12	3R77P623J	Composition: 62,000 ohms ±5%, 1/2 w.	RT3A	19B209284P12	Disc: 600 ohms DC res; sim to GE 16D2134.
C73C	5491601P127	Phenolic: 2.4 pf ±5%, 500 VDCW.	R13	3R77P124K	Composition: 0.12 megohm ±10%, 1/2 w.	RT3B	19B209284P9	Disc: 330 ohms DC res; sim to GE 16D3119.
C74A	5496219P261	Ceramic disc: 82 pf ±5%, 500 VDCW, temp coef -80 PPM.	R14	3R77P393J	Composition: 39,000 ohms ±5%, 1/2 w.	RT4*	19B209284P13	Rod: 3200 ohms DC res; sim to GE 1R1126. Deleted in 19D413163G7, G8 by REV C.
C74B	5496219P260	Ceramic disc: 75 pf ±5%, 500 VDCW, temp coef	R15	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.			Deleted in 19D413163G9 by REV D.
	5 4000 10 DOS 4	-80 PPM.	R16	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	RT5A	19B209284P12	Disc: 600 ohms DC res; sim to GE 16D2134.
C74C	5496219P254	Ceramic disc: 43 pf ±5%, 500 VDCW, temp coef -80 PPM.	R17 R18	3R77P473K 3R77P103K	Composition: 47,000 ohms ±10%, 1/2 w. Composition: 10,000 ohms ±10%, 1/2 w.	RT5B RT6*	19B209284P9 19B209284P13	Disc: 330 ohms DC res; sim to GE 16D3119. Rod: 3200 ohms DC res; sim to GE 1R1126.
C80 and C81	5494481P11	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R19	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.			Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
C82	19A116080P1	Polyester: 0.01 µf ±20%, 50 VDCW.	R20 and R21	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	RT7A RT7B	19B209284P12 19B209284P9	Disc: 600 ohms DC res; sim to GE 16D2134. Disc: 330 ohms DC res; sim to GE 16D3119.
C83A	5496219P255	Ceramic disc: 47 pf ±5%, 500 VDCW, temp coef -80 PPM.	R21	3R77P681K	Composition: 680 ohms ±10%, 1/2 w.	RT8*	19B209284P13	Rod: 3200 ohms DC res; sim to GE 1813119.
C83B	5496219P250	Ceramic disc: 30 pf ±5%, 500 VDCW, temp coef	R23	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.			Deleted in 19D413163G7, G8 by REV C. Deleted in 19D413163G9 by REV D.
and C83C			R24	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.	RT9	5490828P40	Thermistor: 10,000 ohms ±10%, color code red and white; sim to Globar Type 783H.
C95	19A116080P7	Polyester: 0.1 μf ±20%, 50 VDCW.	R25	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.			and white; sim to Globar Type 705m.
			R26	3R77P473K	Composition: 47,000 ohms ±10%, 1/2 w.			
						-		

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL
			C14
TlA	19D402808G1	Coil, Includes tuning slug 5491798P2.	
TlB	19D402808G2	Coil. Includes tuning slug 5491798P2.	C15
TIC	19D402808G3	Coil. Includes tuning slug 5491798P2.	C16
T2A	19D402808G4	Coil. Includes tuning slug 5491798P2.	C17A
T2B	19D402808G5	Coil. Includes tuning slug 5491798P2.	C17B
T2C	19D402808G6	Coil. Includes tuning slug 5491798P2.	C18A
T3A	19D402808G7	Coil. Includes tuning slug 5491798P2.	C18B
T3B T3C	19D402808G8 19D402808G9	Coil. Includes tuning slug 5491798P2. Coil. Includes tuning slug 5491798P2.	C19
T4A	19D402808G10	Coil. Includes tuning slug 5491798P2.	C20
T4B	19D402808G11	Coil. Includes tuning slug 5491798P2.	C21
T4C	19D402808G12	Coil. Includes tuning slug 5491798P2.	021
T5A R95	19D402808G13 3R152P220K	Coil. Includes tuning slug 5491798P2. Composition: 22 ohms ±10%, 1/4 w.	C22
T5B R95	19D402808G14 3R152P220K	Coil. Includes tuning slug 5491798P2. Composition: 22 ohms ±10%, 1/4 w.	C23
T6A	19D402808G18	Coil. Includes tuning slug 5491798P2.	C24
т6В	19D402808G19	Coil, Includes tuning slug 5491798P2.	C25
T6C	19D402808G20	Coil. Includes tuning slug 5491798P2.	
			C26
XY1 thru		(See Mechanical Parts, RC-2396).	C27A
XY4			C27B and
			C27C
		NOTE: When reordering give GE Part Number and	1 620
		specify exact frequency needed. Crystal freq = Oper. Freq	C29
		12	C30
Yl thru Y4	19B206175P1	Quartz: freq range 2083 to 2750 KHz, temp range -30°C to +85°C. (25-33 MHz)	C31 and
Yl thru Y4	19B206175P2	Quartz: freq range 2750 to 3500 KHz, temp range -30°C to +85°C. (33-42 MHz)	C32 C33
Yl thru	19B206175P3	Quartz: freq range 3500 to 4500 KHz, temp range -30°C to +85°C. (42-50 MHz)	C34A
¥4	-		C34B
A102A thru A102C		PA BOARD A102A 19D416099G4 25-33 MHz A102B 19D416099G5 33-42 MHz	C34C
A102C		A102B 19D416099G5 33-42 MHz A102C 19D416099G6 42-50 MHz	C35
			C36
C2	19Al16655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	
С3	5491601P25	Phenolic: 2.0 pf ±10%, 500 VDCW.	CR1
C4	19A116655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	1
C5	19A116080P10	Polyester: 0.33 µf ±20%, 50 VDCW.	J1
C6	5496267P14	Tantalum: 15 µf ±20%, 20 VDCW; sim to Sprague Type 150D.	thru J5
C8		Part of L3B.	J6
C9		Part of L3C.	J7 and
C10	19A116080P10	Polyester: 0.33 µf ±20%, 50 VDCW.	J8
Clla	19B209408P103	Variable, mica: 7-50 pf, 400 VDCW.	1
C11B	19B209408P102	Variable, mica: 4-25 pf, 400 VDCW.	L1
Clic	19B209408P103	Variable, mica: 7-50 pf, 400 VDCW.	L2
C12	19A116656P68K0	Ceramic disc: 68 pf ±10%, 500 VDCW, temp coef 0 PPM.	
C13	7484398P11	Silver mica: 100 pf ±10%, 500 VDCW; sim to Underwood Type J1HF.	
			1

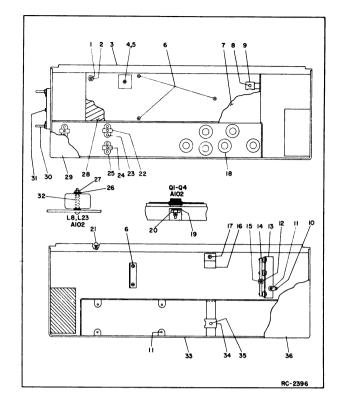
SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL
C14	7484398P10	Silver mica: 68 pf ±10%, 500 VDCW; sim to	L3B
C15	7484398P2	Underwood Type J1HF. Silver mica: 47 pf ±10%, 500 VDCW; sim to Underwood Type J1HF.	
C16	5494481P27	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C8
C17A	19B209408P108	Variable, mica: 70-200 pf, 400 VDCW.	
C17B	19B209408P106	Variable, mica: 37-140 pf, 400 VDCW.	L3C
C18A	19B209408P110	Variable, mica: 100-250 pf, 400 VDCW.	
C18B	19B209408P108	Variable, mica: 70-200 pf, 400 VDCW.	
C19	5496218P21	Ceramic disc: 100 pf ±10%, 500 VDCW, temp coef 0 PPM.	C9
C20	5496218P20	Ceramic disc: 82 pf ±10%, 500 VDCW, temp coef 0 PPM.	
C21	5496218P52	Ceramic disc: 36 pf ±5%, 500 VDCW, temp coef 0 PPM.	L4
C22	5494481P26	Ceramic disc: 5000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	L5
C23	5494481P30	Ceramic disc: 3900 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	L6 L7
C24	5494481P28	Ceramic disc: 2700 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	L8
C25	19A116655P21	Ceramic disc: 2700 pf ±20%, 1000 VDCW; sim to	L9
C26	19A116080P10	RMC Type JF Discap. Polyester: 0.33 µf ±20%, 50 VDCW.	Llo
C27A	19A115917P205	Variable, compression mica: 180-690 pf, 500	L11
C27B	19A115917P204	VDCW; sim to Electro Motive Type 30 M.	L12
and C27C	1941159179204	Variable, compression mica: 100-500 pf, 500 VDCW; sim to Electro Motive Type 30 M.	L13
C28	19A115917P205	Variable, compression mica: 180-690 pf, 500	L14 L15
C29	19A115917P206	VDCW; sim to Electro Motive Type 30 M. Variable, compression mica: 265-880 pf, 500	L16
C30	5496267P14	VDCW; sim to Electro Motive Type 30 M. Tantalum: 15 µf ±20%, 20 VDCW; sim to	L17
C31	19A116656P68KO	Sprague Type 150D. Ceramic disc: 68 pf ±10%, 500 VDCW, temp coef	L18
and C32		O PPM.	L19
C33	19A116656P120K0	Ceramic disc: 120 pf ±10%, 500 VDCW, temp coef 0 PPM.	L20
C34A	7489162P141	Silver mica: 390 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L21
C34B	7489162P135	Silver mica: 220 pf ±10%, 500 VDCW; sim to Electro Motive Type DM-15.	L22 L23
C34C	7489162P31	Silver mica: 150 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	L24
C35		(Part of L27).	L25
C36	19A116656P36J0	Ceramic disc: 36 pf ±5%, 500 VDCW, temp coef	L26
		O PPM.	L27
		DIODES AND RECTIFIERS	1
CR1	19A115250P1	Silicon.	Q1
		JACKS AND RECEPTACLES	Q2
J1 thru J5	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	Q3 and Q4
16	4033513P2	Contact, electrical: sim to Bead Chain L93-2.	
J7	4033513P4	Contact, electrical: sim to Bead Chain L93-3.	R1
and J8			R2
		inductors	R3
Ll	7488079P7	Choke, RF: 1.50 µh ±10%, 0.50 ohms DC res max; sim to Jeffers 4411-10K.	R4 R5
L2	7488079P16	Choke, RF: 10.0 µh ±10%, 0.60 ohms DC res max; sim to Jeffers 4421-7K,	R6
			R7
			R10

YMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
L3B		COIL ASSEMBLY	R11	5490205P15	Composition: 2.7 ohms ±10%, 1 w.
		19D413121G1	R12	5490205P8	Composition: 4.7 ohms ±5%, 1 w.
			R13	3R78P750J	Composition: 75 ohms ±5%, 1 w.
С8	7489162P25	Silver mica: 82 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.	and R14		
- 1	5491798P2	Tuning slug.			CHASSIS
3C		COIL ASSEMBLY 19D413121G2			19D416555G1 25-33 MHz 19D416555G2 33-42 MHz 19D416555G3 42-50 MHz
					19D416555G4 25-33 MHz (WITH CHANNEL GUARI 19D416555G6 42-50 MHz (WITH CHANNEL GUARI
C9	7489162P23	Silver mica: 68 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.			
1	5491798P2	Tuning slug.	C101 thru	5493392P7	Ceramic, feed-thru: 1000 pf +100%-0%, 500 VE sim to Allen Bradley Type FA5C.
L4	7488079P16	Choke, RF: 10 µh ±10%, 0.60 ohms DC res max; sim to Jeffers 4421-7K.	C103		TONE NETWORKS
L5	7491382P101	Coil, RF: 100 mh ±10%, 4 ohms DC res max; sim to Delevan 3500 Series.	FL1	19B205280G	Tone Detector. (Check group numbers for desi
L6	19D413121G3	Coil.		19B205280G1	frequency). 71.9 Hz
L7	19D413121G4	Coil.		G2 G3	77.0 Hz 82.5 Hz
L8	19B216365G1	Coil.		G4 G5	88.5 Hz 94.8 Hz
L9	7488079P1	Choke, RF: 0.15 µh ±20%, 0.03 ohms DC res max; sim to Jeffers 4411-1M.		G6 G7	100.0 Hz 103.5 Hz
L10	19D413121G5	Coil.		G8 G9	107.2 Hz 110.9 Hz
L11	19D413121G6	Coil.		G10 G11	114.8 Hz 118.8 Hz
L12	19D413121G7	Coil.		G12 G13	123.0 Hz 127.3 Hz
L13	19D413121G5	Coil.		G14 G15 G16	131.8 Hz 136.5 Hz 141.3 Hz
L14	19D413121G6	Coil.		G16 G17 G18	141.3 H2 146.2 H2 151.4 H2
15	19D413121G7	Coil.		G19 G20	156.7 Hz 162.2 Hz
5	7488079P67	Choke, RF: 33.0 µh ±10%, 0.56 ohms DC res max; sim to Jeffers 4424-3K.		G21 G22 G23	167,9 Hz 173,8 Hz 179,9 Hz
	7488079P52	Choke, RF: 1.50 µh ±10%, 0.10 ohms DC res max; sim to Jeffers 4414-2K.		G24 G25	186.2 Hz 192.8 Hz
	7488079P67	Choke, RF: 33.0 µh ±10%, 0.56 ohms DC res max; sim to Jeffers 4424-3K.		G26 G30 G31	203.5 Hz 74.4 Hz 79.7 Hz
	7488079P52	Choke, RF: 1.50 µh ±10%, 0.10 ohms DC res max; sim to Jeffers 4414-2K.		G32 G33 G34	85.4 Hz 91.5 Hz 97.4 Hz
10	19A122813P1	Coil.			
L21	19A122813P2	Coil.	FL101A	19D402770G2	Filter: 25-33 MHz.
L22	19A122813P3	Coil.	FL101B	19D402770G2	Filter: 33-42 MHz.
L23	19B216365G1	Coil.	FL101C	19D402770G4	Filter: 42-50 MHz.
L24	19B216108P1	Coil.	FL102	19B216319G2	Filter.
L25	19B216108P2	Coil.			
L26	19B216108P3	Coil.			JACKS AND RECEPTACLES
L27	19D413121G9	Coil.	J101	19C303426G1	Connector: 20 pin contacts.
		TRANSISTORS	J102	19B205689G1	Connector: 18 pin contacts.
Q1	19A116611P1	Silicon, NPN.	J103		(Part of FL101A-FL101C).
Q2	19A116611P2	Silicon, NPN.			
Q3 and Q4	19A116611P3	Silicon, NPN.	P104 and P105	4029840P1	Contact, electrical: sim to AMP 41854.
l		RESISTORS	P105	19B209151P1	Terminal, solderless.
1	3R77P152J	Composition: 1500 ohms ±5%, 1/2 w.	P112	4029840P1	Contact, electrical: sim to AMP 41854.
R2	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	P117	4029840P1	Contact, electrical: sim to AMP 41854.
R3	3R77P200J	Composition: 20 ohms ±5%, 1/2 w.	P119	4029840P1	Contact, electrical: sim to AMP 41854.
R4	3R77P561J	Composition: 560 ohms ±5%, 1/2 w.	thru P121	ļ	
R5	5490205P3	Composition: 3.3 ohms ±10%, 1 w.	P122	4029840P2	Contact, electrical: sim to Amp 42827-2.
R6	5490205P5	Composition: 5.6 ohms ±10%, 1 w.	P123	4029840P1	Contact, electrical: sim to AMP 41854.
R7	3R77P150J	Composition: 15 ohms ±5%, 1/2 w.	Pl26 thru	4029840P1	Contact, electrical: sim to AMP 41854.
	Jarreson	Composition. To stand 10%, 1/2 %.			

LBI-4411A (Cont'd from Page 12)

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
P129	4029840P2	Contact, electrical: sim to Amp 42827-2.	13	19A122827P2	Angle.
P130	4029840P1	Contact, electrical: sim to AMP 41854.	14	19A127071P1	Strap. (Part of R101).
thru P134			15	N44P9005C13	Machine screw: No. 4-40 x 5/16.
			16	19A127296P1	Support.
R101		Includes:	17	N84P9004C6	Screw: No. 4-40 x 1/4.
	19A127071P1	Strap.	18	19A122826P1	Can. (Used with T1-T6 on A101).
	19A127073P1	Slide.	19	5492178P2	Washer, spring tension: sim to Wallace Barnes
R103	19B209022P89	Wirewound: 0.1 ohm ±5%, 2 w; sim to IRC Type BWH.	20	N210P15C6	Hexnut: No. 8-32. (Used with Q1-Q4 on A102).
		SWITCHES	21	N170P16006P2	Cap screw: No. 10-32 x 3/8. (Secures heat sink to chassis).
S101	4031922P1	Push: SPST, normally open, 1/2 amp at 12 VDC;	22	4033089P1	Clip, spring tension. (Part of XY1-XY4).
		sim to Stackpole Type SS-15.	23	19A115793P1	Contact, electrical: sim to Malco 2700. (Part of XY1-XY4).
W101	5491689P83	RF: 500 VDC. Includes 5 inch cable	24	19B200525P9	Rivet. (Part of XY1-XY4).
		(19B209044P19).	25	19C311172P2	Crystal socket. (Part of XY1-XY4),
W102	19A127143G3 4029840P2	RF: approx 16 inches. Includes: Contact, electrical: sim to Amp 42827-2.	26	7147306P2	Insulated bushing: sim to H.H. Smith Inc 2150. (Used with L8, L23 on AlO2).
	4029840P1	Contact, electrical: sim to AMP 41854.	27	7141225P3	Hex nut: No. 6-32. (Used with L8, L23 on Al02).
	102501011	contact, electrical: Sim to Amp 41854.	28	19C311816G2	Heat sink. (Used with AlO2).
W103	19A121948G2	Cable, RF: approx 6-1/2 inches long. Includes (P2, P7, and P8).	29	19C303396G1	Mobile Top Cover.
W104	19A121948G3	Cable, RF: approx 10 inches long. Includes		19C303495G8	Station Top Cover. (Except Repeaters and VM).
		(Pl, P7, and P8).		19C303673G3	Station Top Cover. (Repeaters and VM only).
			30	19A121676P1	Guide pin.
			31	19A115793P1	Contact, electrical: sim to Malco 2700. (Located on Cl03, J101).
		HARNESS ASSEMBLY 19D416555G7	32	7150727P14	Tubing vinyl. (Specify length when ordering).
		(Includes J101, J102, P104-P106, P112, P117, P119-P123, P126-P134, W104).	33	19B205206G5	Chassis,
			34	7160861P4	Nut, sheet spring: sim to Tinnerman C6452- 8Z-67.
		CHANNEL GUARD MODIFICATION 19A122552G1 25-33 MHz	35	N115P1508C13	Flathead screw: No. 8-18 x 1/2. (Secures bottom cover).
		19A122552G2 33-50 MHz	36	19C303396G3	Mobile Bottom Cover.
				19C303495G7	Station Bottom Cover.
сззв	5490008P143	Silver mica: 470 pf ±10%, 300 VDCW; sim to Electro Motive Type DM-15.			
C38	19A116080P7	Polyester: 0.1 µf ±20%, 50 VDCW.			
C39	5496267P9	Tantalum: 3.3 µf ±20%, 15 VDCW; sim to			
		Sprague Type 150D.			
R35	19B209358P107	Variable, carbon film: approx 75 to 25,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.			
R36	3R77P223K	Composition: 22,000 ohms ±10%, 1/2 w.			
		MECHANICAL PARTS (SEE RC-2396)			
1	19B201074P208	Tap screw: No. 4-40 x 1/2.			
2	19A122092P3	Stop,			
3	19C311781P1	Heat sink.			
4	7115130P6	Lockwasher: sim to Shakeproof 1214.			
5	4032272P4	Hexnut, brass: No. 1/4-40. (Located on far side of C27 and C28).			
6	19B201074P205	Tap screw: No. 4-40 x 5/16.			
7	19B216290G2	Cover.			
8	N113P1306C	Tap screw: No. 6-18 x 3/8.			
9	7160861P16	Nut, sheet spring: sim to Tinnerman C8091- 632-157.			
10	4036994P1	Terminal, solder: sim to Zierick Mfg Corp 505.			
11	19B201074P304	Tap screw: 6-32 x 1/4.			
12	19A127073P1	Slide, (Part of R101).			
j					
İ					





PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A & B - Exciter Board 19D413163G1, 2, 4, 5, 7, 8, 10, 11, 13, 14, 15, 16, 17, 18

Incorporated into initial shipment.

REV. A thru C - Exciter Board 19D413163G3, 6, 9, 12
Incorporated into initial shipment.

REV. D - To improve temperature compensation. Deleted C7, C18, C22, C44, RT2, RT4, RT6, RT8.

REV. C - Exciter Board 19D413163G1, 2, 4, 5, 7, 8, 10, 11, 13, 14, 15, 16, 17, 18

To improve temperature compensation. Deleted C7, C18, C22, C44, RT2, RT4, RT6, RT8.

PARTS LIST

LBI-3938C

CHANNEL GUARD ENCODER MODEL 4EH18A10 19B216161G1

SYMBOL	GE PART NO.	DESCRIPTION
Cl	5496267P1	Tantalum: 6.8 μf ±20%, 6 VDCW; sim to Sprague Type 150D.
C2	19B209243P15	Polyester: 0.22 µf ±20%, 250 VDCW.
C3	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
		DIODES AND RECTIFIERS
CR1 and CR2	5494922P1	Silicon.
		TONE NETWORKS
FL1	19B205280 G1 G2 G3 G4 G5 G6 G7 G8 G9 G10 G11 G12 G13 G14 G15 G16 G17 G18 G19 G20 G21 G22 G23 G24 G25 G26	Tone Detector. (Check group numbers for desired frequency). 71.9 Hz 77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Hz 100.0 Hz 107.2 Hz 110.9 Hz 114.8 Hz 118.8 Hz 123.0 Hz 123.0 Hz 136.5 Hz 141.3 Hz 141.3 Hz 146.2 Hz 156.7 Hz 162.2 Hz 167.9 Hz 179.9 Hz 186.2 Hz 186.2 Hz 186.2 Hz 186.2 Hz 186.2 Hz 186.2 Hz
	İ	JACKS AND RECEPTACLES
Jl thru J4	4033513P4	Contact, electrical: sim to Bead Chain L93-3.
		TRANSISTORS
Q1 thru Q3	19A115362P1	Silicon, NPN; sim to Type 2N2925.
Rl	3R77P244J	Composition: .24 megohm ±5%, 1/2 w.
R2	3R77P682J	Composition: 6800 ohms ±5%, 1/2 w.
R3	19A116278P233	Metal film: 2150 ohms ±2%, 1/2 w.
R4	19A116278P65	Metal film: 46.4 ohms ±2%, 1/2 w.
R5	19A116278P301	Metal film: 10,000 ohms ±2%, 1/2 w.
R6	19A116278P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R7	19A116278P412	Metal film: 0.13 megohm ±2%, 1/2 w.
R8	19A116278P285	Metal film: 7500 ohms ±2%, 1/2 w.
R9	19A116278P117	Metal film: 147 ohms ±2%, 1/2 w.
R10	19A116278P269	Metal film: 5110 ohms ±2%, 1/2 w.
R11	3R77P102J	Composition: 1000 ohms ±5%, 1/2 w.
R12	19A116278P365	Metal film: 46,400 ohms ±2%, 1/2 w.

SYMBOL	GE PART NO.	DESCRIPTION
RT1	5490828P36	Thermistor: 55,000 ohms ±10%, color code black/red; sim to Globar Type 723-B.
W1	19A121920G3	Cable assembly. Includes socket (XFL1), approx 4.25 inches long.
XFL1	19B216186G1 4029840P2 4029840P1	(Part of W1). MISCELLANEOUS Cable assembly. (Connects to J1 thru J4). Contact, electrical: sim to Amp 42827-2. (Connects to J1, J3, J4). Contact, electrical: sim to AMP 41854. (Connects to J2).

*COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES

14 *COMPONEN

DESCRIPTION

DESCRIPTION

Thermistor: 55,000 ohms ±10%, color code black/red, sim to Globar Type 723-B.

Cable assembly. Includes socket (XFL1), approx 4.25 inches long.

(Part of W1).

Cable assembly. (Connects to 11 them M4)

ORDERING SERVICE PARTS

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component
- 2. Description of part
- 3. Model number of equipment
- 4. Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ◆ LYNCHBURG, VIRGINIA 24502

